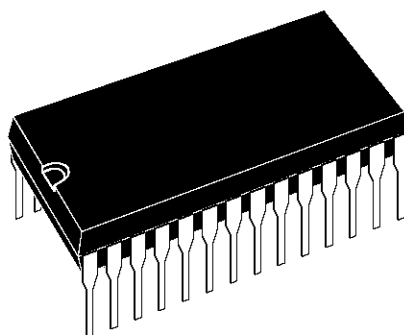
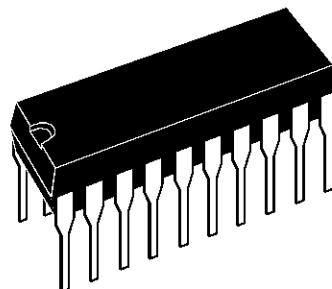


**8-BIT HCMOS MCUs WITH A/D CONVERTER
WITH AUTOMOTIVE TEMPERATURE RANGE**

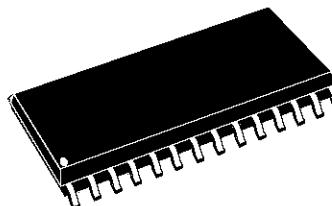
- 3.0 to 6.0V Supply Operating Range
- 4 MHz Maximum Clock Frequency
- -40 to +125°C Operating Temperature Range
- Run, Wait, Stop Modes
- 5 different interrupt vectors
- Look-up table capability in ROM
- User ROM: 1828 bytes (ST6210B, 15B)
3876 bytes (ST6220B, 25B)
- Data ROM: User selectable size
(in program ROM)
- Data RAM: 64 bytes
- ROM readout Protection
- PDIP20, PSO20 (ST6210B, 20B) packages
- PDIP28, PSO28 (ST6215B, 25B) packages
- 12/20 fully software programmable I/O as:
 - Input with pull-up resistor
 - Input without pull-up resistor
 - Input with interrupt generation
 - Open-drain or push-pull outputs
 - Analog Inputs
- 4 I/O lines can sink up to 15mA for direct LED or TRIAC driving
- 8 bit counter with a 7-bit programmable prescaler
- Digital Watchdog and Oscillator Safe Guard
- 8 bit A/D Converter with up to 8 (ST6210B, 20B) and up to 16 (ST6215B, 25B) analog inputs
- On-chip clock oscillator driven by Quartz Crystal, Ceramic resonator or RC network
- Power-on Reset
- One external not maskable interrupt
- 9 powerful addressing modes
- The development tool of the ST621xB, 2xB microcontrollers consists of the ST626x-EMU emulation and development system connected via an RS232 serial line to an MS-DOS PC



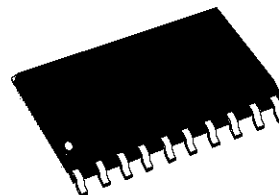
PDIP28



PDIP20



PSO28



PSO20

(Ordering Information at the end of the datasheet)

INTRODUCTION

ROM devices of the ST62X1B and ST622XB family are available in extended Automotive temperature range -40°, 125° (Suffix 3). All the functionalities remain the same as in Consumer (Suffix 1) and Industrial (Suffix 6) temperature ranges while electrical characteristics are redefined.

No OTP device are available for this range of temperature.

THE READER IS ASKED TO REFER TO THE DATASHEET OF ST621XB AND ST622XB FOR COMPLETE FUNCTIONAL DESCRIPTION.

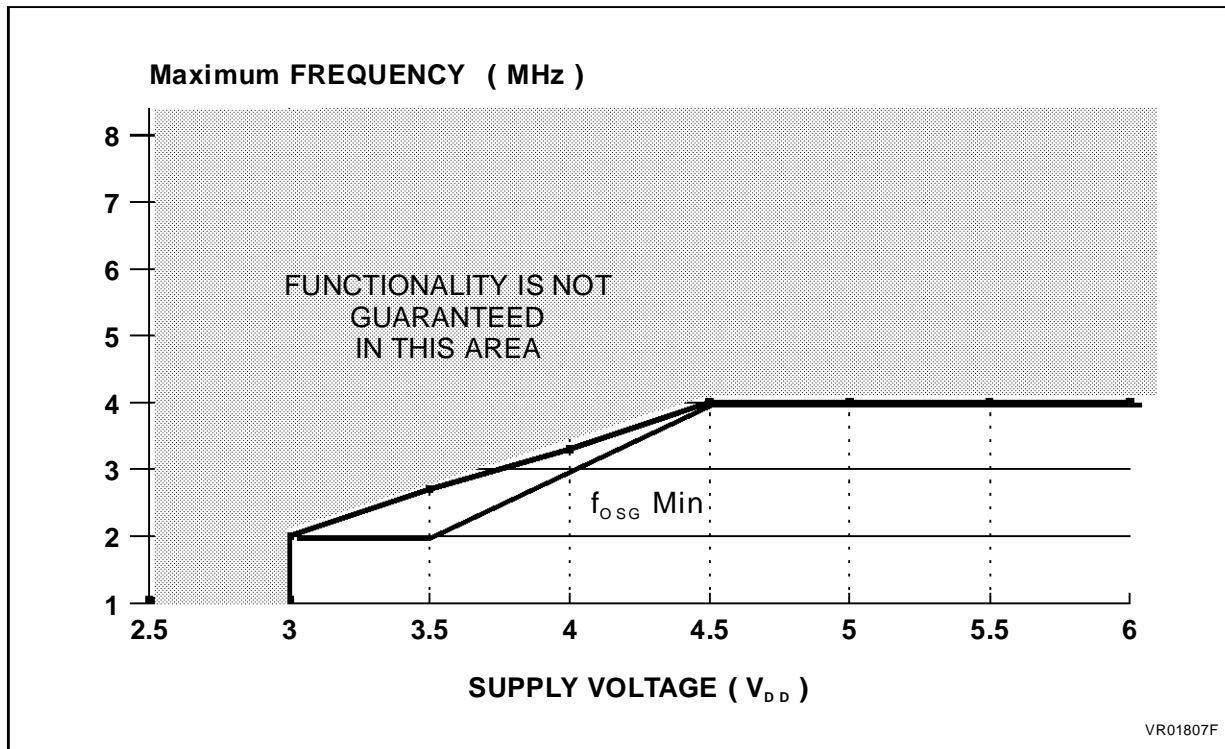
RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
T _A	Operating Temperature	3 Suffix Version	-40		125	°C
V _{DD}	Operating Supply Voltage	f _{OSC} = 2MHz f _{INT} = 2MHz	3.0		6.0	V
		f _{OSC} = 4MHz f _{INT} = 4MHz	4.5		6.0	V
f _{INT}	Internal Frequency ⁽³⁾	V _{DD} = 3V; OSG disabled	0		2.0	MHz
		V _{DD} = 4.5V;OSG disabled	0		4.0	MHz
I _{INJ+}	Pin Injection Current (positive) Digital Input ⁽¹⁾ Analog Inputs ⁽²⁾	V _{DD} = 4.5 to 5.5V			+5	mA
I _{INJ-}	Pin Injection Current (negative) Digital Input ⁽¹⁾ Analog Inputs	V _{DD} = 4.5 to 5.5V			-5	mA

Notes :

1. A current of ± 5mA can be forced on each pin of the digital section without affecting the functional behaviour of the device. For a positive current injected into one pin, a part of this current (~ 10%) can be expected to flow from the neighbouring pins.
2. If a total current of +1 mA is flowing into the single analog channel or if the total current flowing into all the analog inputs is of 1mA, all the resulting conversions are shifted by +1 LSB. If a total positive current is flowing into the single analog channel or if the total current flowing into all the analog inputs is of 5mA, all the resulting conversions are shifted by +2 LSB.
3. An internal frequency above 1MHz is recommended for reliable A/D results.

Maximum Operating FREQUENCY (Fmax) Versus SUPPLY VOLTAGE (V_{DD})



The shade area is outside the ST6210B/15B operating range, device functionality is not guaranteed.

DC ELECTRICAL CHARACTERISTICS

 (T_A = -40 to +125°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
V _{IL}	Input Low Level Voltage TIMER,NMI,RESET pins				V _{DD} x 0.3	V
V _{IH}	Input High Level Voltage TIMER,NMI,RESET pins		V _{DD} x 0.7			V
V _{Hys}	Hysteresis Voltage ⁽⁴⁾ All Inputs	V _{DD} = 5V V _{DD} = 3V		1 0.5		V
V _{OL}	Low Level Output Voltage TIMER pin	I _{OL} = + 5.0mA			0.2 x V _{DD}	V
V _{OH}	High Level Output Voltage TIMER pin	I _{OH} = - 5.0mA	V _{DD} x 0.65			V
R _{PU}	Pull-up TIMER, NMI pins		50	100	200	kΩ
I _{IL} I _{IH}	Input Leakage Current ⁽¹⁾ TIMER, NMI pins	V _{IN} = V _{SS} V _{IN} = V _{DD}		0.1	1.0	μA
I _{IL} I _{IH}	Input Leakage Current RESET pin	V _{IN} =V _{DD} ; Watchdog Res. V _{IN} =V _{DD} ; No Watch. Res. V _{IN} =V _{SS} ; External Res.	-8	-16	1 10 -30	mA μA μA
I _{DD}	Supply Current in RESET Mode	V _{RESET} = V _{SS} f _{OSC} = 4MHz			3.5	mA
	Supply Current in RUN Mode ⁽²⁾	V _{DD} = 5.0V f _{INT} =4MHz V _{DD} = 5.0V f _{INT} =f _{LFAO} V _{DD} = 3.0V f _{INT} =2MHz			3.5 TBD TBD	mA
	Supply Current in WAIT Mode ⁽³⁾	V _{DD} = 5.0V f _{INT} =4MHz V _{DD} = 5.0V f _{INT} =f _{LFAO} V _{DD} = 3.0V f _{INT} =2MHz			1.50 TBD TBD	mA
	Supply Current in STOP Mode ⁽³⁾	I _{LOAD} = 0mA V _{DD} = 5.0V			20	μA

Notes :

1. Only when pull-ups are not inserted
2. All peripherals running
3. A/D Converter in Stand-by
4. Hysteresis voltage between switching levels

AC ELECTRICAL CHARACTERISTICS

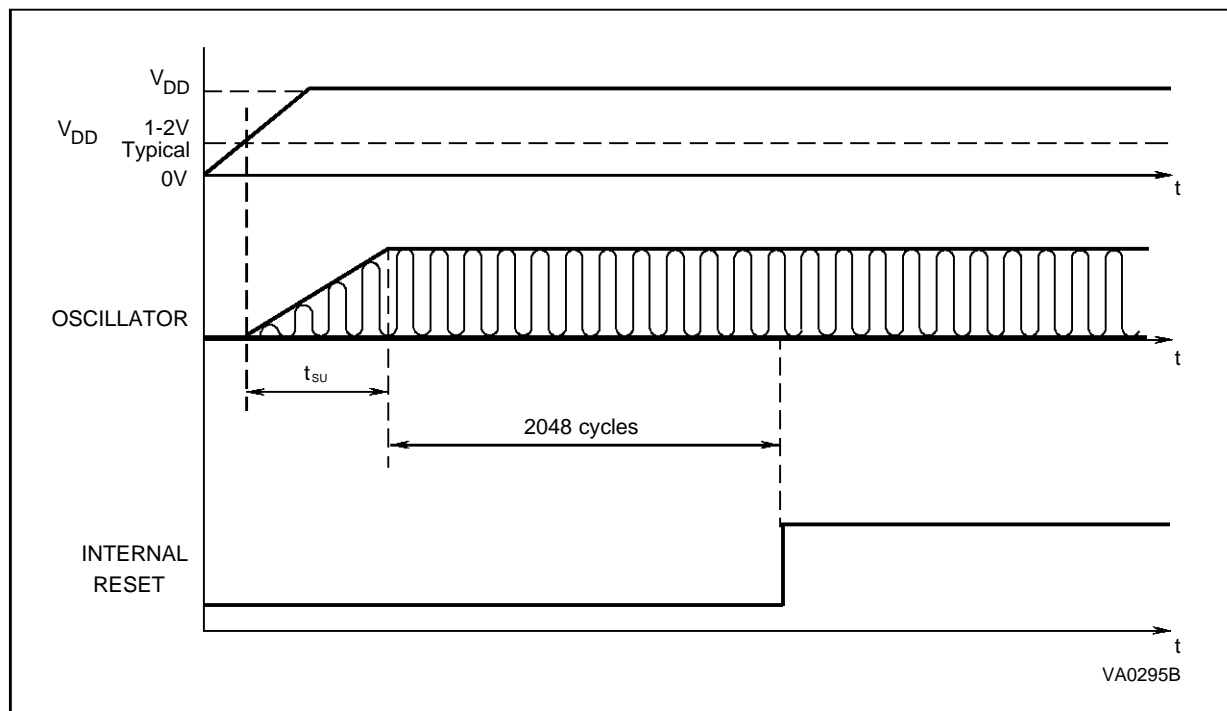
(T_A = -40 to +125°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
f _{OSC}	Oscillator Frequency	V _{DD} = 3.0V; OSG disabled V _{DD} = 4.5V; OSG disabled			2 4	MHz
f _{OSG}	Internal frequency with OSG enabled	V _{DD} = 3.0V; F _{OSC} =2MHz V _{DD} = 4.5V; F _{OSC} =4MHz	2 4			MHz
f _{LFAO}	Low Frequency Auxiliary Oscillator		200	400	800	kHz
t _{SU}	Oscillator Start-up Time at Power On ⁽²⁾	Ceramic Resonator C _{L1} = C _{L2} = 22pF		5	100	ms
t _{SUS}	Oscillator STOP mode Recovery Time ⁽²⁾	4MHz Ceramic Resonator CL1=CL2=22pF		0.2	100	
		4MHz Quartz CL1=C _{L2} =22pF		10	100	
t _{REC}	Supply Recovery Time ⁽¹⁾		100			
T _{WR}	Minimum Pulse Width (V _{DD} = 5V) RESET pin NMI pin		100 100			ns
C _{IN}	Input Capacitance	All Inputs Pins			10	pF
C _{OUT}	Output Capacitance	All Outputs Pins			10	pF

Note:

1. Period for which V_{DD} has to be connected at 0V to allow internal Reset function at next power-up.
2. See Figure 38. This value is highly dependent on the Ceramic Resonator or Quartz Crystal used in the application.

Figure 38. Power On Reset



ST6210Bx3-15Bx3-20Bx3-25Bx3

I/O PORT CHARACTERISTICS

(T_A = -40 to +125°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
V _{IL}	Input Low Level Voltage	I/O Pins			0.3x V _{DD}	V
V _{IH}	Input High Level Voltage	I/O Pins	0.7x V _{DD}			V
V _{OL}	Low Level Output Voltage	V _{DD} = 5.0V I _{OL} = 10μA, All I/O Pins I _{OL} = 3mA, Standard I/O I _{OL} = 7mA I _{OL} = 15mA			0.1 0.8 0.8 1.3	V
V _{OH}	High Level Output Voltage	I _{OH} = -10μA I _{OH} = -3mA, V _{DD} = 5.0V I _{OH} = -1.0mA, V _{DD} = 3.0V	V _{DD} -0.1 3.5 2.0			V

TIMER CHARACTERISTICS

(T_A = -40 to +85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
t _{RES}	Resolution		$\frac{12}{f_{INT}}$			s
f _{IN}	Input Frequency on TIMER Pin	Stop Mode Run and Wait Modes			2 $\frac{f_{INT}}{8}$	MHz MHz
t _w	Pulse Width at TIMER Pin	V _{DD} = 3.0V V _{DD} = 4.5V V _{DD} = 5.5V	1 250 250			μs ns ns

A/D CONVERTER CHARACTERISTICS

(T_A= -40 to +125°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Res	Resolution			8		Bit
A _{TOT}	Total Accuracy ^{(1) (2)}	f _{OSC} > 1.2MHz			±2	LSB
		f _{OSC} > 32kHz	To be defined			
t _C	Conversion Time	f _{OSC} = 4MHz		140		µs
V _{AN}	Conversion Range		V _{SS}		V _{DD}	V
ZIR	Zero Input Reading	Conversion result when V _{IN} = V _{SS}	00			Hex
FSR	Full Scale Reading	Conversion result when V _{IN} = V _{DD}			FF	Hex
AD _I	Analog Input Current During Conversion	V _{DD} = 4.5V			1.0	µA
AC _{IN} ⁽³⁾	Analog Input Capacitance			2	5	pF
ASI	Analog Source Impedance	Analog Channel switched just before conversion start ⁽⁴⁾			30	kΩ

Notes:

1. Noise at V_{DD}, V_{SS} < 10mV
2. With oscillator frequencies less than 1MHz, the A/D Converter accuracy is decreased.
3. Excluding Pad Capacitance.
4. ASI can be increased as long as the load of the A/D Converter input capacitor is ensured before conversion start.

ST6210Bx3-15Bx3-20Bx3-25Bx3

ORDERING INFORMATION TABLE

Sales Type	ROM x8	I/O	Additional Features	Temperature Range	Package
ST6210BB3/XXX	2K Bytes	12	A/D CONVERTER	-40 to +125°C	PDIP20
ST6210BM3/XXX				-40 to +125°C	PSO20
ST6215BB3/XXX		20	A/D CONVERTER	-40 to +125°C	PDIP28
ST6215BM3/XXX				-40 to +125°C	PSO28
ST6220BB3/XXX	4K Bytes	12	A/D CONVERTER	-40 to +125°C	PDIP20
ST6220BM3/XXX				-40 to +125°C	PSO20
ST6225BB3/XXX		20	A/D CONVERTER	-40 to +125°C	PDIP28
ST6225BM3/XXX				-40 to +125°C	PSO28

Note: /XXX is a 3 alphanumeric character code added to the generic sales type on receipt of a ROM code and valid options.

Notes:

Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without the express written approval of SGS-THOMSON Microelectronics.

© 1995 SGS-THOMSON Microelectronics - All rights reserved.

Purchase of I²C Components by SGS-THOMSON Microelectronics conveys a license under the Philips I²C Patent. Rights to use these components in an I²C system is granted provided that the system conforms to the I²C Standard Specification as defined by Philips.

SGS-THOMSON Microelectronics Group of Companies

Australia - Brazil - France - China - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco
The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.